# Dual Non-Inverting Schmitt Trigger Buffer

The NL27WZ17 is a high performance dual buffer operating from a 1.65 to 5.5 V supply. At  $V_{CC} = 3.0$  V, high impedance TTL compatible inputs significantly reduce current loading to input drivers while the TTL compatible outputs offer improved switching noise performance.

# Features

- Extremely High Speed:  $t_{PD}$  2.0 ns (typical) at  $V_{CC} = 5.0$  V
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Overvoltage Tolerant Inputs
- LVTTL Compatible Interface Capability with 5.0 V TTL Logic with  $V_{CC} = 3.0 \text{ V} (2.7-3.3)$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability at  $V_{CC} = 3.0 \text{ V}$
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 72; Equivalent Gate = 18
- Pb–Free Package is Available







Figure 2. Logic Symbol

# **PIN ASSIGNMENT**

IN A1
GND
IN A2
OUT Y2
V <sub>CC</sub>
OUT Y1

A Input	Y Output					
L	L					
н	Н					

**FUNCTION TABLE** 



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SC-88/SOT-363/SC-70 DF SUFFIX CASE 419B

# MARKING DIAGRAM



# ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# MAXIMUM RATINGS

Symbol		Characteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \leq V_{l} \leq +7.0$	V
Vo	DC Output Voltage	Output in Z or LOW State (Note 1)	$-0.5 \le V_O \le 7.0$	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>I</sub> < GND	- 50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>O</sub> < GND	- 50	mA
lo	DC Output Sink Current		±50	mA
I <sub>CC</sub>	DC Supply Current per Suppl	y Pin	±100	mA
I <sub>GND</sub>	DC Ground Current per Grou	nd Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
PD	Power Dissipation in Still Air		200	mW
$\theta_{JA}$	Thermal Resistance		333	°C/W
TL	Lead Temperature, 1 mm fror	n case for 10 s	260	°C
TJ	Junction Temperature under I	Bias	+ 150	°C
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 150 N/A	V
I <sub>Latch</sub> Up	Latch–Up Performance	Above $V_{CC}$ and Below GND at 85°C (Note 5)	±500	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.
I<sub>O</sub> absolute maximum rating must be observed.
Tested to EIA/JESD22-A114-A
Tested to EIA/JESD22-A115-A

Tested to JESD22–C101–A
 Tested to EIA/JESD78

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parar	Parameter			
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	(High or LOW State)	0	5.5	V
T <sub>A</sub>	Operating Free–Air Temperature		- 40	+ 85	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 V \pm 0.2 V V_{CC} = 3.0 V \pm 0.3 V V_{CC} = 5.0 V \pm 0.5 V$	0 0 0	No Limit No Limit No Limit	ns/V

# DC ELECTRICAL CHARACTERISTICS

			V <sub>cc</sub>	٦	「 <sub>A</sub> = 25°0	2	$-40^{\circ}C \leq 10^{\circ}$	T <sub>A</sub> ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>T</sub> +	Positive Input Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.6 1.0 1.2 1.3 1.9 2.2	1.0 1.5 1.7 1.9 2.7 3.3	1.4 1.8 2.0 2.2 3.1 3.6	0.6 1.0 1.2 1.3 1.9 2.2	1.4 1.8 2.0 2.2 3.1 3.6	V
V <sub>T</sub> -	Negative Input Threshold Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.2 0.4 0.5 0.6 1.0 1.2	0.5 0.75 0.87 1.0 1.5 1.9	0.8 1.15 1.4 1.5 2.0 2.3	0.2 0.4 0.5 0.6 1.0 1.2	0.8 1.15 1.4 1.5 2.0 2.3	V
V <sub>H</sub>	Input Hysteresis Voltage		1.65 2.3 2.7 3.0 4.5 5.5	0.1 0.25 0.3 0.4 0.6 0.7	0.48 0.75 0.83 0.93 1.2 1.4	0.9 1.1 1.15 1.2 1.5 1.7	0.1 1.25 0.3 0.4 0.6 0.7	0.9 1.1 1.15 1.2 1.5 1.7	V
V <sub>OH</sub>	High–Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$\begin{split} I_{OH} &= -100 \ \mu A \\ I_{OH} &= -3.0 \ m A \\ I_{OH} &= -8.0 \ m A \\ I_{OH} &= -12 \ m A \\ I_{OH} &= -16 \ m A \\ I_{OH} &= -24 \ m A \\ I_{OH} &= -32 \ m A \end{split}$	1.65–5.5 1.65 2.3 2.7 3.0 3.0 4.5	V <sub>CC</sub> -0.1 1.29 1.9 2.2 2.4 2.3 3.8	V <sub>CC</sub> 1.52 2.1 2.4 2.7 2.5 4.0		V <sub>CC</sub> -0.1 1.29 1.9 2.2 2.4 2.3 3.8		V
V <sub>OL</sub>	Low–Level Output Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 100 \ \mu A$ $I_{OL} = 4.0 \ m A$ $I_{OL} = 8.0 \ m A$ $I_{OL} = 12 \ m A$ $I_{OL} = 16 \ m A$ $I_{OL} = 24 \ m A$ $I_{OL} = 32 \ m A$	1.65–5.5 1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		$\begin{array}{c} 0.1 \\ 0.24 \\ 0.3 \\ 0.4 \\ 0.4 \\ 0.55 \\ 0.55 \end{array}$	V
I <sub>IN</sub>	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			±0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off–Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1.0		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		10	μΑ

# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

			v <sub>cc</sub>	٦	Γ <sub>A</sub> = 25°C	2	$-40^{\circ}C \leq -$	$T_A \leq 85^\circ C$	
Symbol	Parameter	Condition	(Ŭ)	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input A to Y	$R_L = 1.0 \text{ M}\Omega, C_L = 15 \text{ pF}$	$\begin{array}{c} 1.65 \\ 1.8 \\ 2.5 \pm 0.2 \\ 3.3 \pm 0.3 \\ 5.0 \pm 0.5 \end{array}$	2.0 2.0 1.0 1.0 0.5	9.1 7.6 5.0 3.7 3.1	15 12.5 9.0 6.3 5.2	2.0 2.0 1.0 1.0 0.5	15.6 13 9.5 6.5 5.5	ns
		$R_L = 500 \ \Omega, \ C_L = 50 \ pF$	$\begin{array}{c} 3.3\ \pm\ 0.3\\ 5.0\ \pm\ 0.5 \end{array}$	1.5 0.8	4.4 3.7	7.2 5.9	1.5 0.8	7.5 6.2	

# **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V},$ $V_{I} = 0 \text{ V or } V_{CC}$	7.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10 MHz, $V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$ 10 MHz, $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	9.0 11	pF



Figure 3. Switching Waveforms

A 1-MHz square input wave is recommended for propagation delay tests.

OUTPUT

 $V_{CC}$ 

 $V_T +$ 

V<sub>T</sub>-

GND

VOH

 $V_{\mathsf{OL}}$ 

Figure 4. Test Circuit



Figure 5. Typical Input Threshold,  $V_T$  +,  $V_T$  - versus Power Supply Voltage





(b) A Schmitt-Trigger Offers Maximum Noise Immunity

Figure 6. Typical Schmitt-Trigger Applications

# NL27WZ17

# **ORDERING INFORMATION**

			Device No	menclature					
Device	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Package	Shipping $^{\dagger}$	
NL27WZ17DFT2	NL	2	7	WZ	17	DFT2	SC-88	3000 / Tape & Reel	
NL27WZ17DFT2G	NL	2	7	WZ	17	DFT2	SC-88	3000 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **NL27WZ17**

## PACKAGE DIMENSIONS

SC-88/SOT-363/SC-70 DF SUFFIX CASE 419B-02 ISSUE 02U







NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.071	0.087	1.80	2.20		
В	0.045	0.053	1.15	1.35		
С	0.031 0.043 0.80		0.80	1.10		
D	0.004	0.012	0.10	0.30		
G	0.026	6 BSC	0.65 BSC			
н		0.004		0.10		
J	0.004	0.010	0.10	0.25		
κ	0.004	0.012	0.10	0.30		
Ν	0.008 REF		0.20 REF			
S	0.079	0.087	2.00	2.20		

## SOLDERING FOOTPRINT\*



## SC-88/SC70-6/SOT363

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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